NSN 5961-01-017-0392

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-017-0392
Inclosure Material:
Ceramic
Overall Length:
0.315 inches
Overall Height:
0.190 inches
Overall Width:
0.400 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
4.00 amperes drain current pascal
Maximum Operating Tempurature Per Measurement Point:
115.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
2 pin and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0